

N-Ch MOSFET

General Description

The WSK150N12 is the highest performance trench N-ch MOSFET with extreme high cell density , which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSK150N12 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

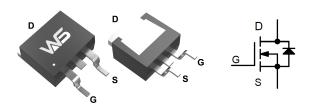
Product Summery

BVDSS	RDSON	ID
120V	5mΩ	150A

Applications

- High Frequency Point-of-Load Synchronous Buck Converter
- Networking DC-DC Power System

TO-263-2L Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	120	V
V_{GS}	Gate-Source Voltage	±20	V
I _D	Continuous Drain Current, V _{GS} @ 10V(T _C =25 °C)	150	Α
I _{DM}	Pulsed Drain Current	330	А
EAS	Single Pulse Avalanche Energy	400	mJ
P _D	Total Power Dissipation _C =25 °C)	192	W
RθJA	Thermal resistance, junction-ambient	62	°C/W
RθJC	Thermal resistance, junction-case	0.65	°C/W
T _{STG}	Storage Temperature Range	-55 to 155	$^{\circ}$ C
T_J	Operating Junction Temperature Range	-55 to 155	$^{\circ}$ C

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Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	120			V
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =30A		5.0	6.5	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}$, $I_D=250uA$	2.0		4.0	V
I _{DSS}	Drain-Source Leakage Current	V _{DS} =120V , V _{GS} =0V , T _J =25°C			1	uA
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20 V$, V_{DS} = $0 V$			±100	nA
Qg	Total Gate Charge	V _{DS} =50V , V _{GS} =10V , I _D =15A		68.9		
Q _{gs}	Gate-Source Charge			18.1		nC
Q _{gd}	Gate-Drain Charge			15.9		
T _{d(on)}	Turn-On Delay Time	V _{DD} =50V , V _{GS} =10V R _G =2Ω, I _D =25A		30.3		
Tr	Rise Time			33.0		
T _{d(off)}	Turn-Off Delay Time			59.5		ns
T _f	Fall Time			11.7		
C _{iss}	Input Capacitance	V _{DS} =50V , V _{GS} =0V , f=1MHz		5823		
Coss	Output Capacitance			778.3		pF
C _{rss}	Reverse Transfer Capacitance			17.5		

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _S	Continuous Source Current ^{1,6}	V _G =V _D =0V , Force Current			150	Α
I _{SM}	Pulsed Source Current ^{2,6}				330	Α
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =25A , T _J =25℃			1.3	٧

■ Note

- ¹) Repetitive rating; pulse width limited by max. junction temperature.
- 2) Pd is based on max. junction temperature, using junction-case thermal resistance.
- 3) The value of R0JA is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with Ta=25 °C.
- 4) VDD=50 V, RG=50 $\Omega,$ L=0.3 mH, starting Tj=25 °C.
- ⁵) Calculated continuous current based on maximum allowable junction temperature.



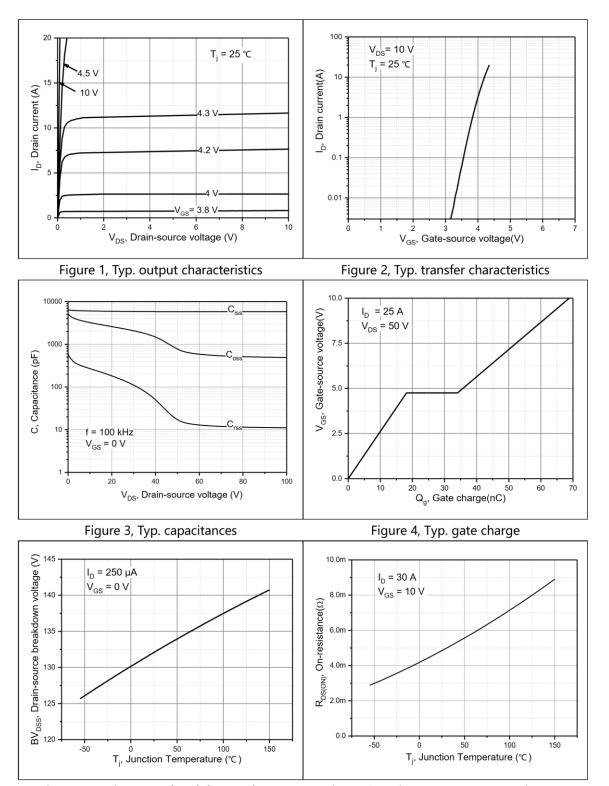


Figure 5, Drain-source breakdown voltage

Figure 6, Drain-source on-state resistance



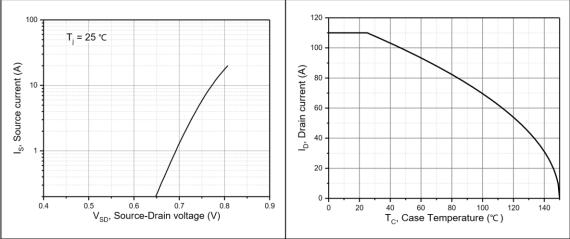


Figure 7, Forward characteristic of body diode

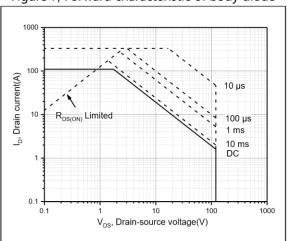


Figure 9, Safe operation area T_C=25 °C

Figure 8, Drain current



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